



100V N-Channel Enhancement Mode MOSFET

Voltage

100 V

Current

7.0 A

Features

- RDS(ON), VGS@10V, ID@7.0A<25mΩ
- RDS(ON), VGS@4.5V, ID@5.0A<28.5mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9458AL

Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	100	٧	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		7.0	А	
	T _A =70°C	I _D	5.6		
Pulsed Drain Current (Note 1)		I _{DM}	28	А	
Power Dissipation	T _A =25°C	1	2.5	107	
	T _A =70°C	P_{D}	1.6	W	
Single Pulse Avalanche Energy (Note 5)		E _{AS}	8.5	mJ	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	ပ	
Typical Thermal resistance - Junction to Ambient, $t \le 10s^{\text{(Note 6)}}$		$R_{\theta JA}$	50	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	100	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.8	2.5	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =7.0A	-	20	25	mΩ		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V,I _D =5.0A	-	22	28.5	mΩ		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =80V, V_{GS} =0V	-	-	1.0	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)	Dynamic (Note 7)							
Total Gate Charge	Q_g	V _{DS} =50V, I _D =7.0A, V _{GS} =10V ^(Note 1,2)	-	31	-	nC		
Gate-Source Charge	Q_gs		-	5.1	-			
Gate-Drain Charge	Q_gd		-	7.3	-			
Input Capacitance	Ciss	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	-	1519	-	pF		
Output Capacitance	Coss	V _{DS} =30V, V _{GS} =0V, f=1.0MHZ	-	132	-			
Reverse Transfer Capacitance	Crss		-	66	-			
Turn-On Delay Time	td _(on)	V_{DD} =50V, I_{D} =7.0A, V_{GS} =10V, R_{G} =3 Ω (Note 1,2)	-	11	-	ns		
Turn-On Rise Time	tr		-	42	-			
Turn-Off Delay Time	td _(off)		-	40	-			
Turn-Off Fall Time	tf		-	19	-			
Drain-Source Diode								
Maximum Continuous Drain-Source					7.0	А		
Diode Forward Current	I _S		_	_				
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.7	1.2	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH, I_{AS} =13A, V_{DD} =50V, V_{GS} =10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

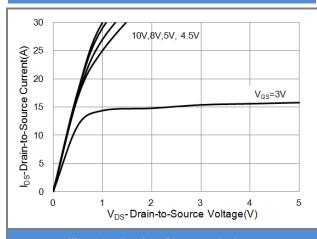


Fig.1 On-Region Characteristics

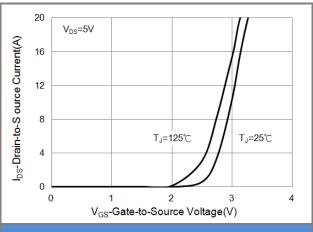


Fig.2 Transfer Characteristics

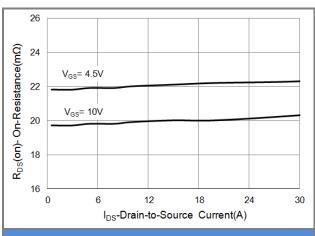


Fig.3 On-Resistance vs. Drain Current

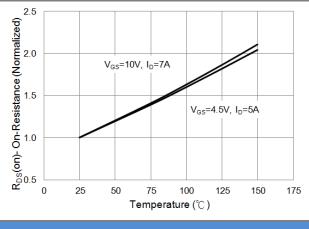


Fig.4 On-Resistance vs. Junction temperature

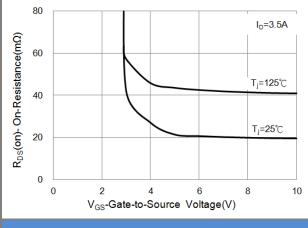


Fig.5 On-Resistance Variation with VGS.

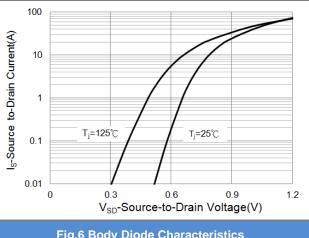


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

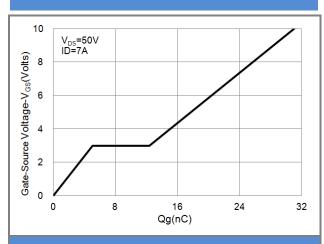
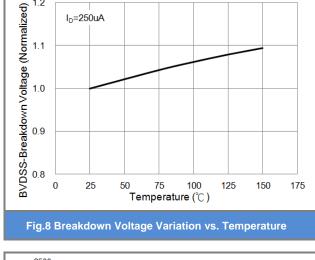


Fig.7 Gate-Charge Characteristics



I_D=250uA

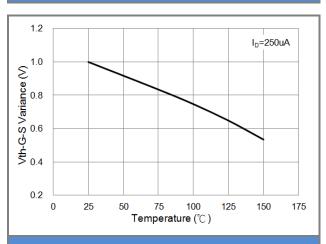


Fig.9 Threshold Voltage Variation with Temperature.

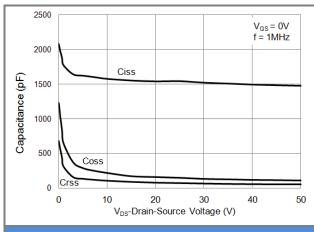
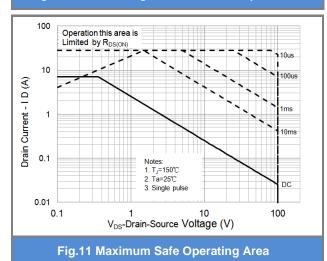


Fig.10 Capacitance vs. Drain-Source Voltage.







TYPICAL CHARACTERISTIC CURVES

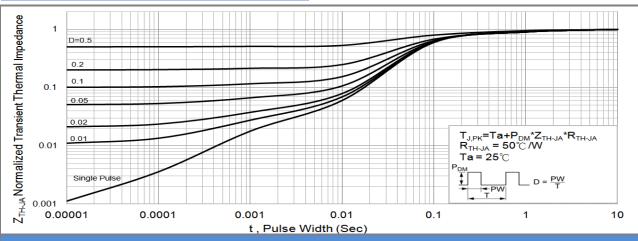


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

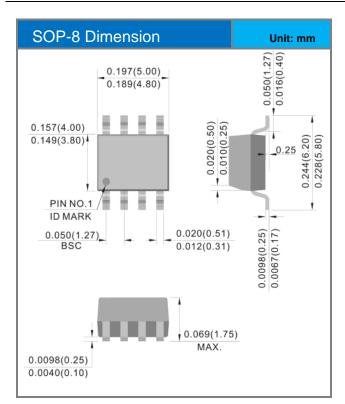


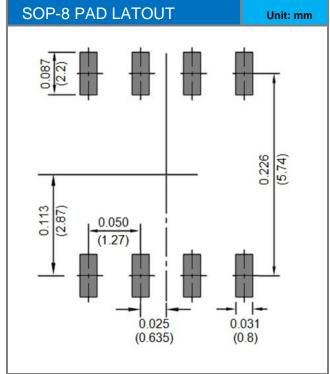


PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9458AL_R2_00001	SOP-8	2.5K pcs / 13" reel	L9458AL	Halogen free

Packaging Information & Mounting Pad Layout









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